

1N4448W

Technical Data Data Sheet N0578, Rev. A



1N4448W FAST SWITCHING DIODE



Features

- High Conductance
- Fast Switching
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose and Switching Application
- Plastic Material –UL Recognition Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams(approx.)
- Marking: T5

Maximum Ratings @T_A=25°C unless otherwise specified

Characteristic	Symbol	1N4448W	Units
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RSM Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current(Note 1)	IF	500	mA
Average Rectified Output Current(Note 1)	lo	250	mA
Peak Forward Surge Current @t=1.0us @t=1.0s	I _{FSM}	4.0 2.0	A
Power Dissipation(Note 1)	Pd	500	mW
Typical Thermal Resistance, Junction to Ambient Air(Note 1)	R _{ejA}	357	K/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Circuit Diagram





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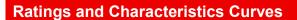
1N4448W

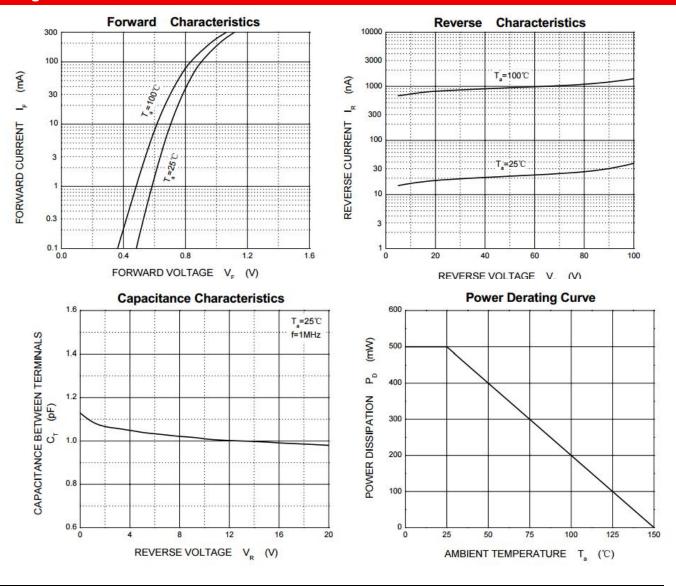


Electrical Characteristics @T_A=25°C unless otherwise specified

Cha	aracteristic	Symbol	1N4448W	Units
Forward Voltage	@I⊧= 5mA @I⊧=10mA	V _{FM}	0.72 1.0	V
Reverse Leakage Current	@V _R =20V @V _R =75V	I _{RM}	25 5.0	nA uA
Junction Capacitance (V _R =0V, f=1.0MHz)		Cj	4.0	pF
Reverse Recovery Time(Note 2)		trr	4.0	ns

Note: 1. Valid provided that terminals are kept at ambient temperature. 2. Measured with $I_F=I_R=10mA$, $I_{RR}=0.1 \times I_R$, $R_L=100\Omega$



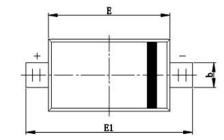


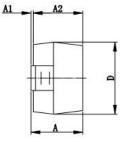
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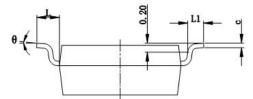


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Mechanical Dimensions SOD-123







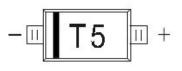
OVMDOL	Millimeters		Inches	
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
с	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF.		0.020 REF.	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

Ordering Information

Device	Package	Shipping
1N4448W	SOD-123	2000000 / rool
111444077	(Pb-Free)	3000pcs / reel

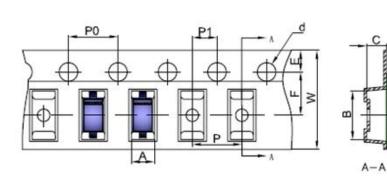
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



T5 = Marking code

Carrier Tape Specification SOD-123



EVMPOL	Millimeters		
SYMBOL	Min.	Max.	
A	1.80	1.90	
В	3.89	3.99	
С	1.52	1.62	
d	1.45	1.65	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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